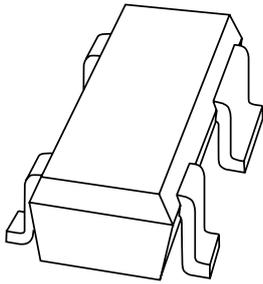


# DATA SHEET



## **BGA2001** Silicon MMIC amplifier

Product specification  
Supersedes data of 1999 Jul 23

1999 Aug 11

# Silicon MMIC amplifier

# BGA2001

### FEATURES

- Low current, low voltage
- Very high power gain
- Low noise figure
- Integrated temperature compensated biasing
- Supply and RF output pin combined.

### APPLICATIONS

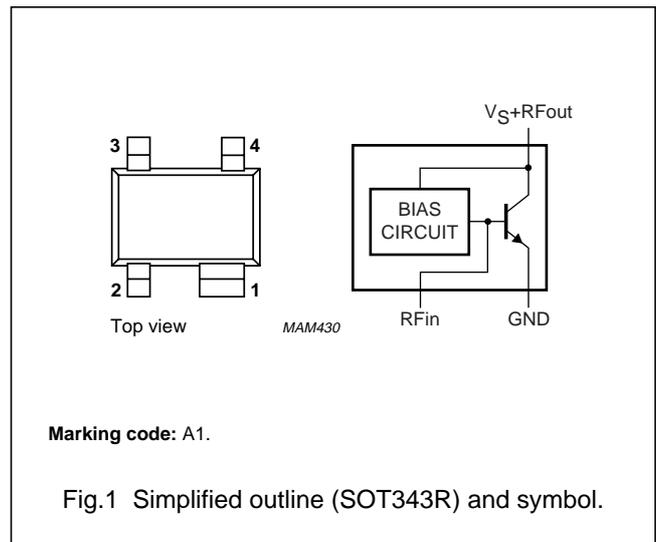
- RF front end
- Wideband applications, e.g. analog and digital cellular telephones, cordless telephones (PHS, DECT, etc.)
- Radar detectors
- Low noise amplifiers
- Satellite television tuners (SATV)
- High frequency oscillators.

### DESCRIPTION

Silicon MMIC amplifier consisting of an NPN double polysilicon transistor with integrated biasing for low voltage applications in a plastic, 4-pin dual-emitter SOT343R package.

### PINNING

PIN	DESCRIPTION
1	GND
2	RF in
3	GND
4	V <sub>S</sub> + RFout



### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>S</sub>	DC supply voltage	RF input AC coupled	–	4.5	V
I <sub>S</sub>	DC supply current	V <sub>V<sub>S</sub>-OUT</sub> = 2.5 V; RF input AC coupled	4.5	–	mA
MSG	maximum stable gain	V <sub>V<sub>S</sub>-OUT</sub> = 2.5 V; f = 1.8 GHz; T <sub>amb</sub> = 25 °C	19.5	–	dB
NF	noise figure	V <sub>V<sub>S</sub>-OUT</sub> = 2.5 V; f = 1.8 GHz; Γ <sub>S</sub> = Γ <sub>opt</sub>	1.3	–	dB

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## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_S$	supply voltage	RF input AC coupled	–	4.5	V
$I_S$	supply current (DC)	forced by DC voltage on RF input	–	30	mA
$P_{tot}$	total power dissipation	$T_s \leq 100\text{ °C}$	–	135	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	operating junction temperature		–	150	°C

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	350	K/W

## CHARACTERISTICS

RF input AC coupled;  $T_j = 25\text{ °C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_S$	supply current	$V_{VS-OUT} = 1\text{ V}$	–	0.7	–	mA
		$V_{VS-OUT} = 2.5\text{ V}$	3	4.5	6	mA
		$V_{VS-OUT} = 4.5\text{ V}$	–	11	–	mA
MSG	maximum stable gain	$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4\text{ mA}$ ; $f = 900\text{ MHz}$	–	22	–	dB
		$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4\text{ mA}$ ; $f = 1.8\text{ GHz}$	–	19.5	–	dB
$ s_{21} ^2$	insertion power gain	$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4\text{ mA}$ ; $f = 900\text{ MHz}$	–	18	–	dB
		$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4\text{ mA}$ ; $f = 1.8\text{ GHz}$	–	14	–	dB
$P_L$	load power	at 1 dB gain compression point; $V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4.4\text{ mA}$ ; $f = 900\text{ MHz}$ ;	–	–2	–	dBm
NF	noise figure	$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4\text{ mA}$ ; $f = 900\text{ MHz}$ ; $\Gamma_S = \Gamma_{opt}$	–	1.3	–	dB
		$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4\text{ mA}$ ; $f = 1.8\text{ GHz}$ ; $\Gamma_S = \Gamma_{opt}$	–	1.3	–	dB
IP3 <sub>(in)</sub>	input intercept point; note 1	$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4.4\text{ mA}$ ; $f = 900\text{ MHz}$	–	–7.4	–	dBm
		$V_{VS-OUT} = 2.5\text{ V}$ ; $I_{VS-OUT} = 4.5\text{ mA}$ ; $f = 1800\text{ MHz}$	–	–4.5	–	dBm

## Note

- See application note: RNR-T45-99-B-0513.

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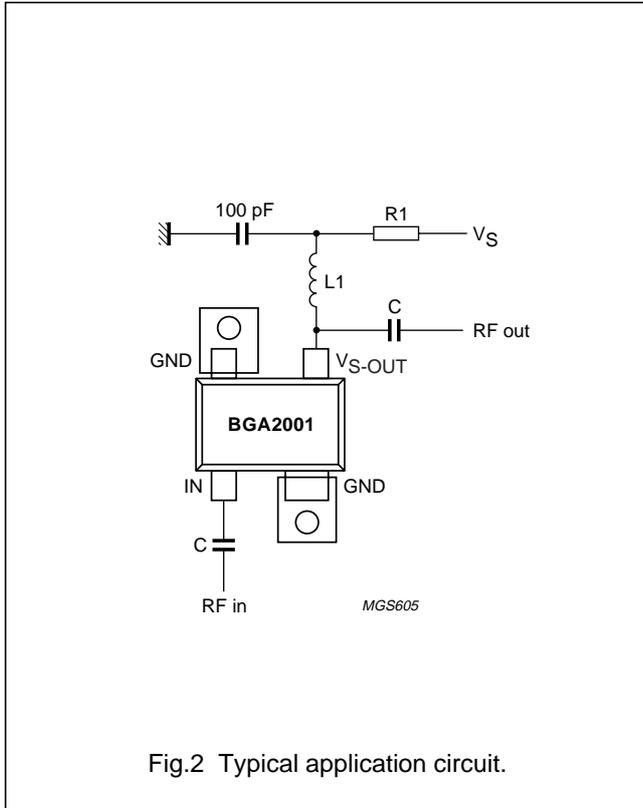


Fig.2 Typical application circuit.

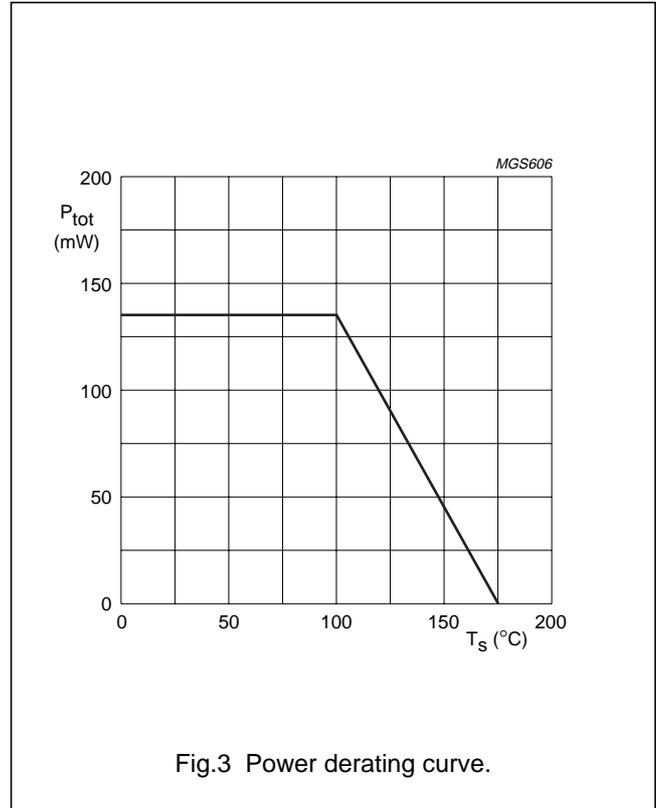


Fig.3 Power derating curve.

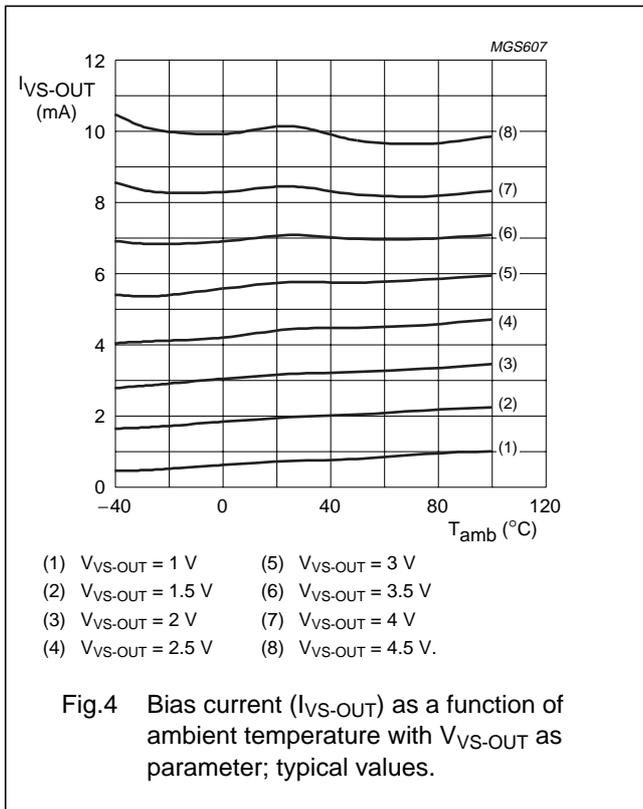


Fig.4 Bias current ( $I_{VS-OUT}$ ) as a function of ambient temperature with  $V_{VS-OUT}$  as parameter; typical values.

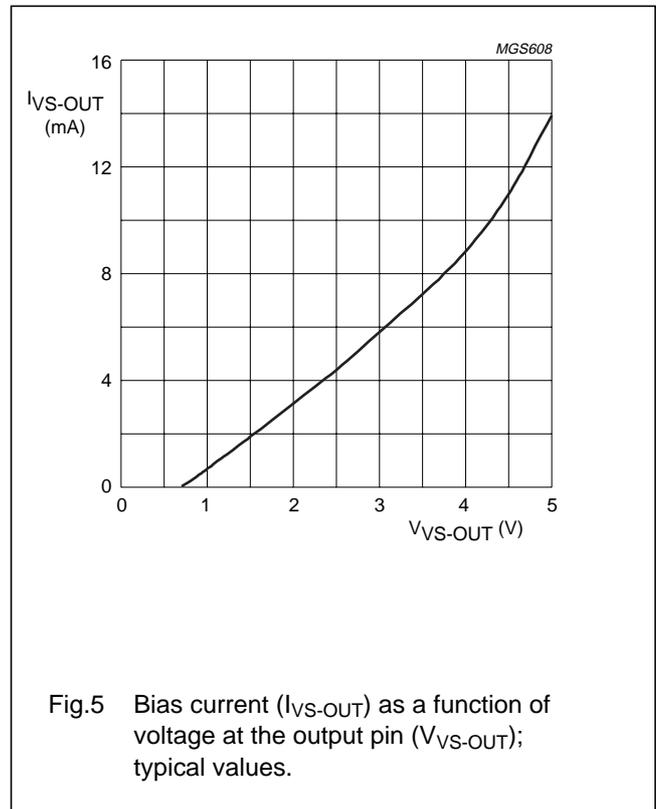
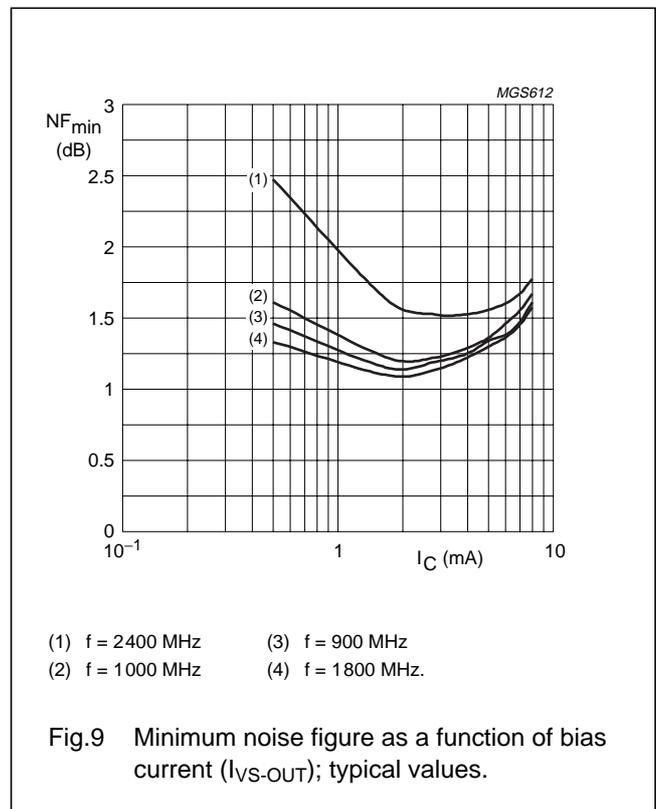
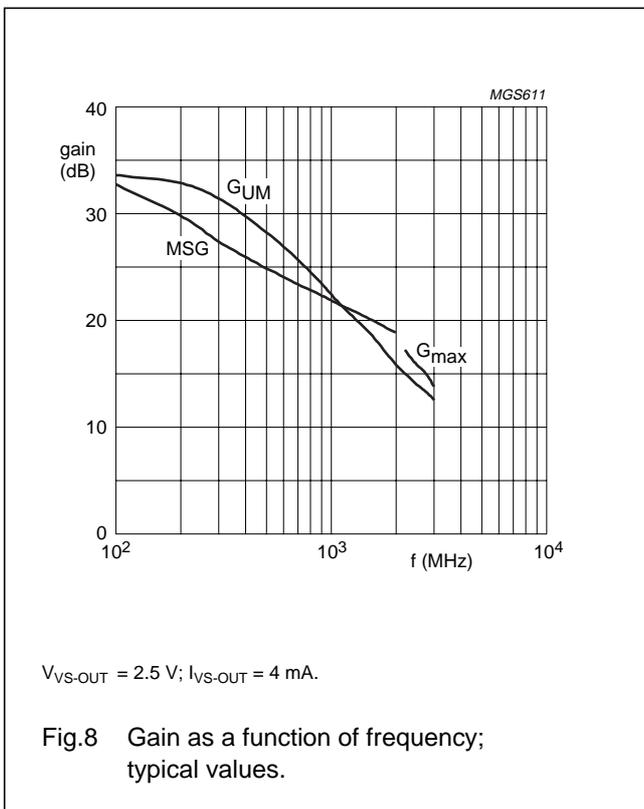
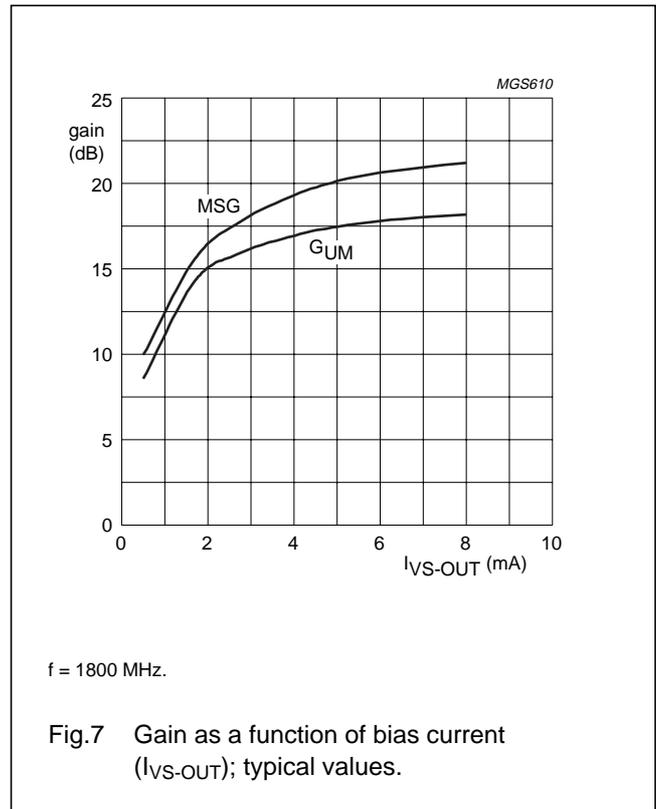
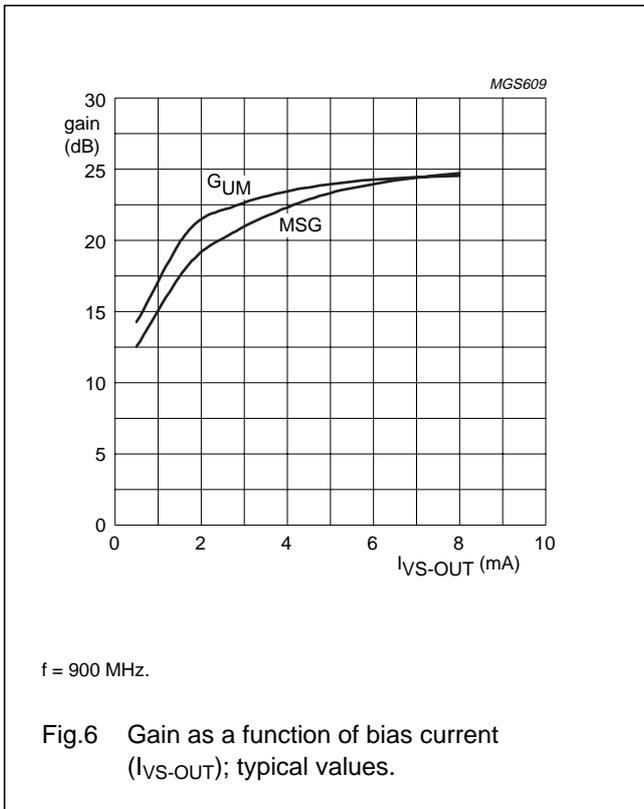


Fig.5 Bias current ( $I_{VS-OUT}$ ) as a function of voltage at the output pin ( $V_{VS-OUT}$ ); typical values.

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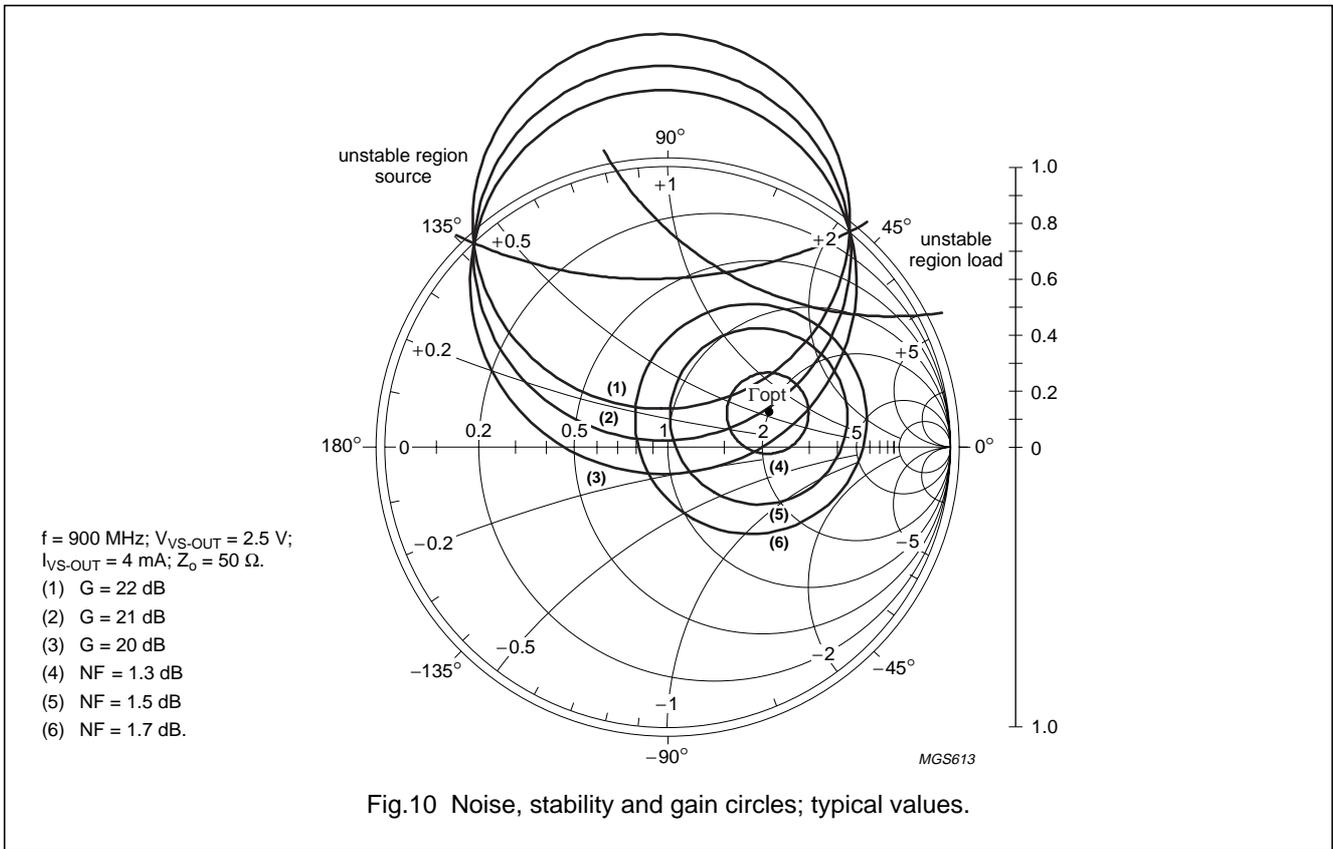


Fig.10 Noise, stability and gain circles; typical values.

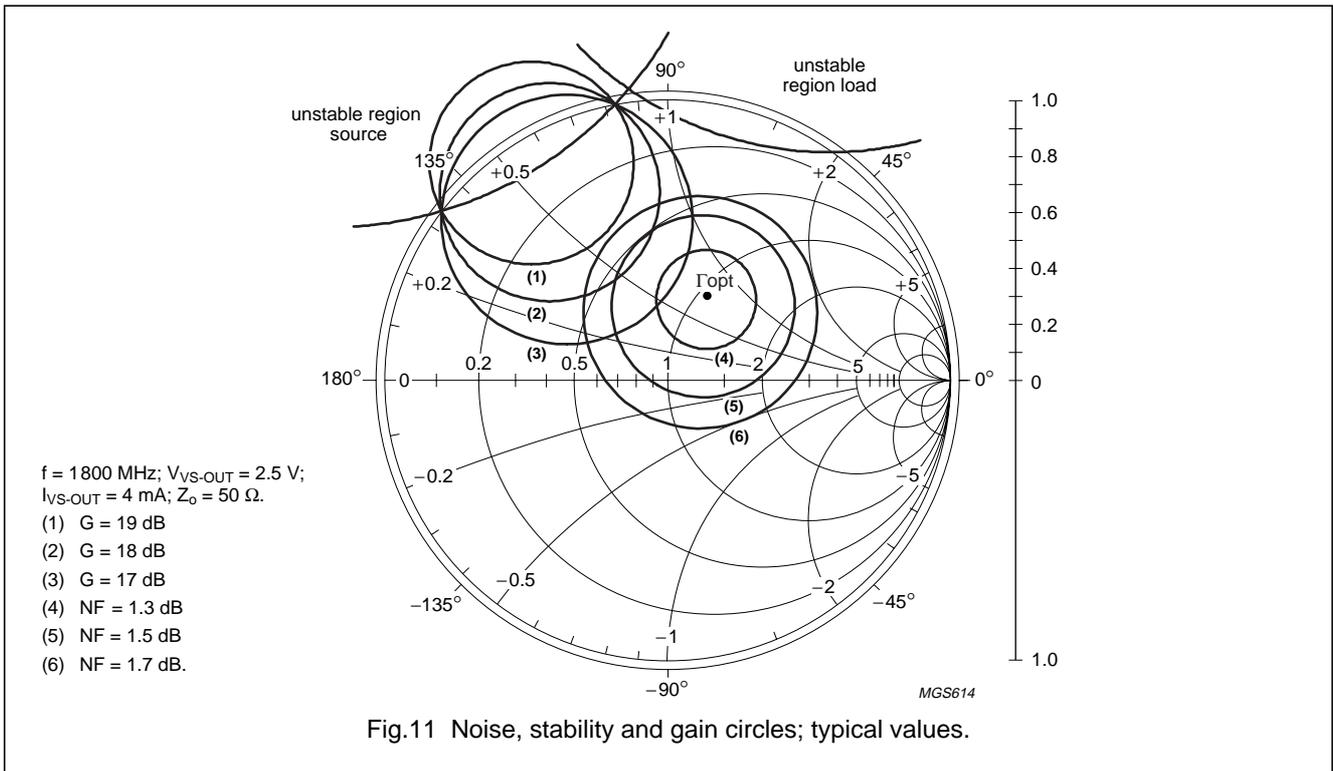
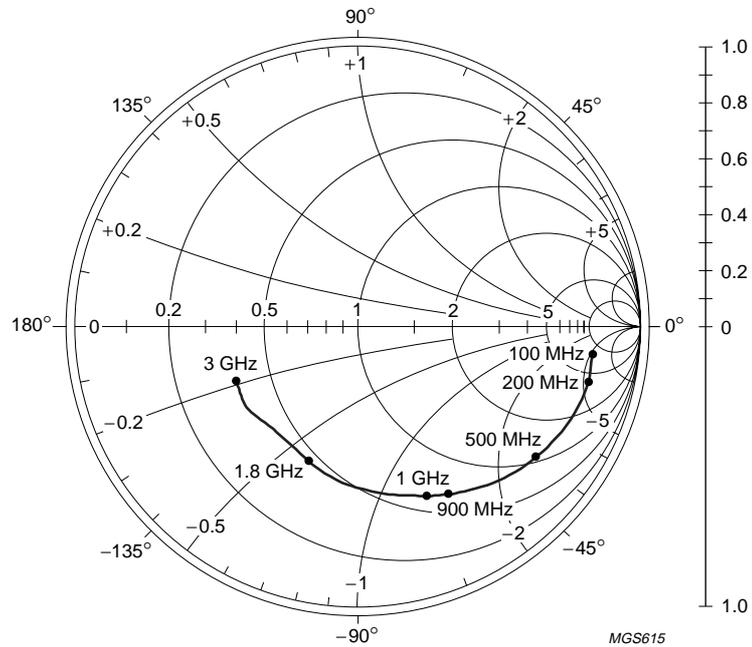


Fig.11 Noise, stability and gain circles; typical values.

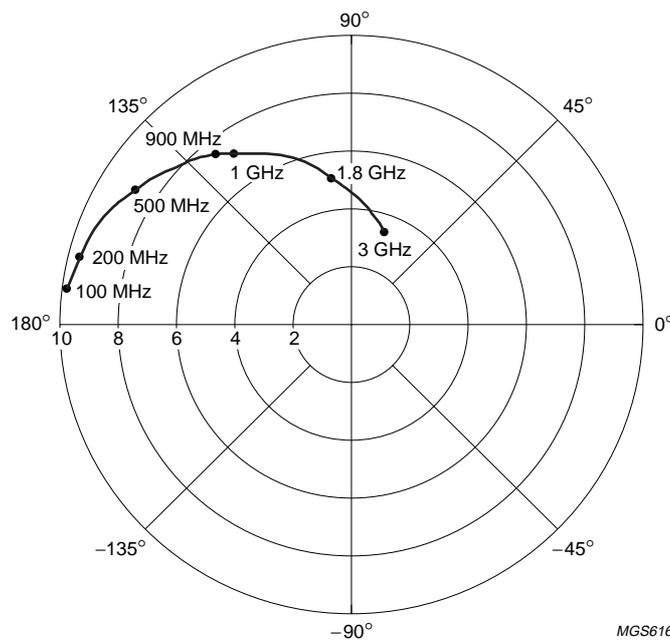
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$V_{VS-OUT} = 2.5\text{ V}$ ;  $I_{VS-OUT} = 4\text{ mA}$ ;  $Z_0 = 50\ \Omega$ .

Fig.12 Common emitter input reflection coefficient ( $s_{11}$ ); typical values.

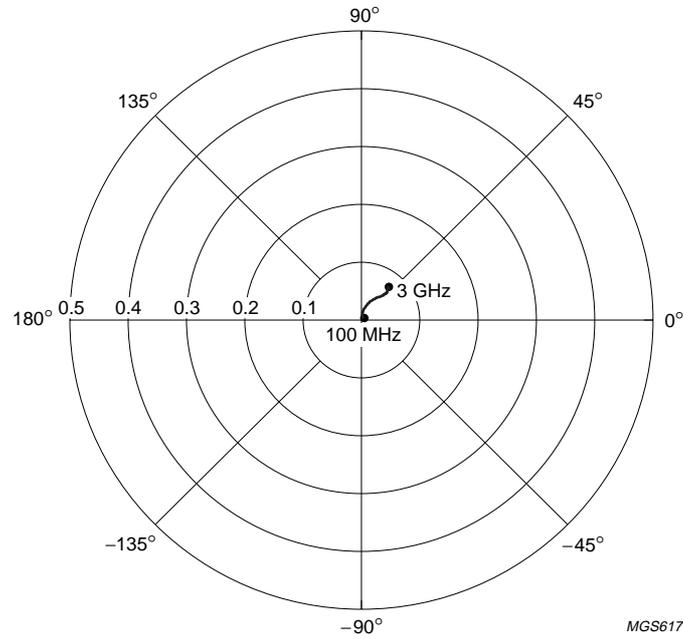


$V_{VS-OUT} = 2.5\text{ V}$ ;  $I_{VS-OUT} = 4\text{ mA}$ ;  $Z_0 = 50\ \Omega$ .

Fig.13 Common emitter forward transmission coefficient ( $s_{21}$ ); typical values.

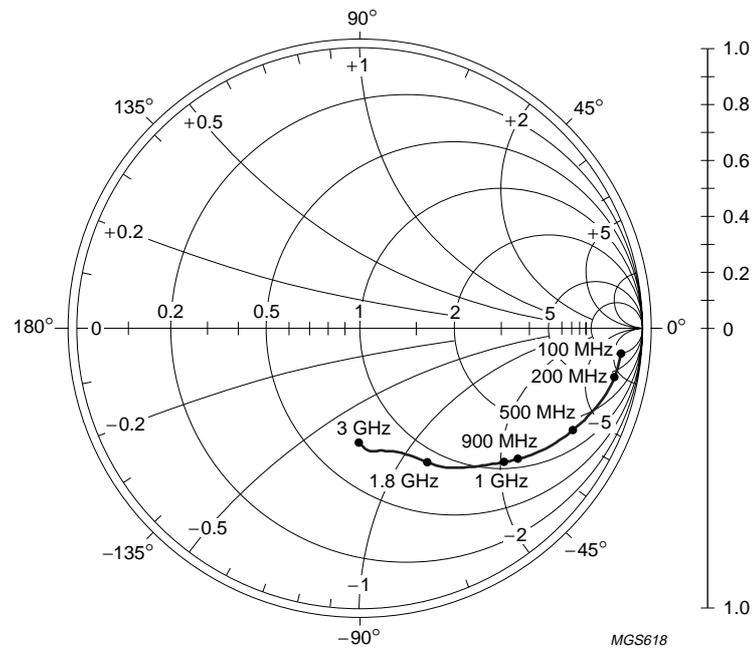
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$V_{VS-OUT} = 2.5\text{ V}$ ;  $I_{VS-OUT} = 4\text{ mA}$ ;  $Z_o = 50\ \Omega$ .

Fig.14 Common emitter reverse transmission coefficient ( $s_{12}$ ); typical values.



$V_{VS-OUT} = 2.5\text{ V}$ ;  $I_{VS-OUT} = 4\text{ mA}$ ;  $Z_o = 50\ \Omega$ .

Fig.15 Common emitter output reflection coefficient ( $s_{22}$ ); typical values.

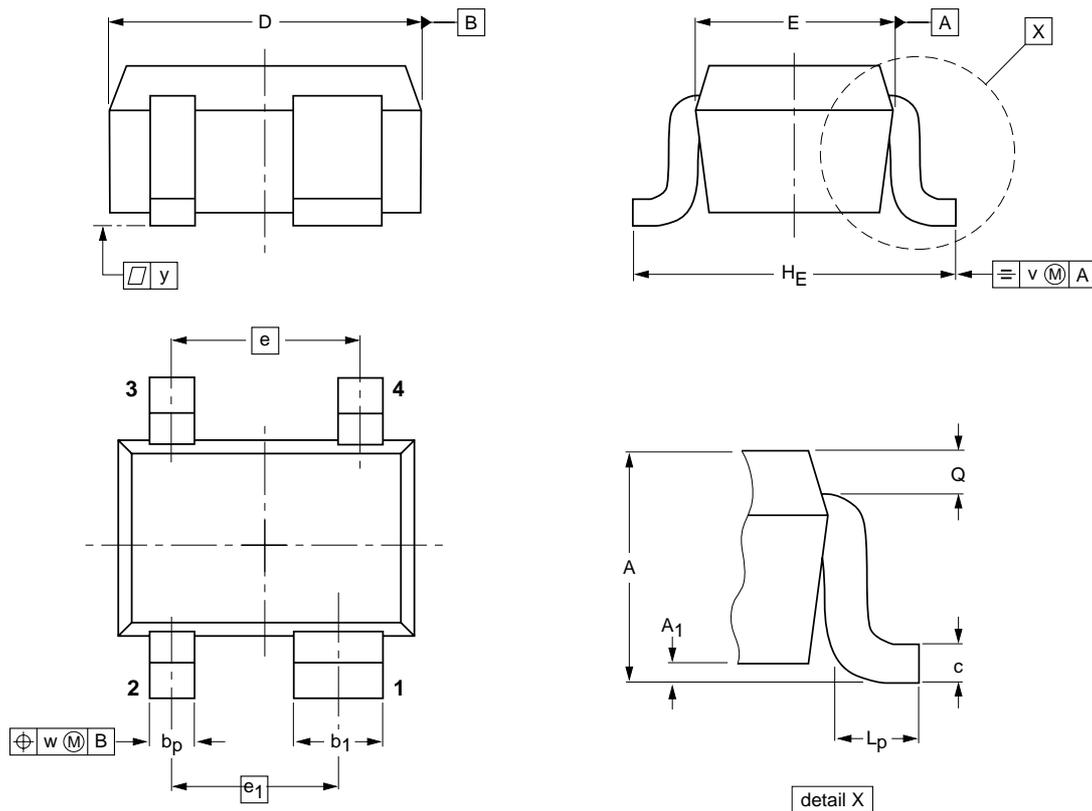
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PACKAGE OUTLINE

Plastic surface mounted package; reverse pinning; 4 leads

SOT343R



DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max	b <sub>p</sub>	b <sub>1</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w	y
mm	1.1 0.8	0.1	0.4 0.3	0.7 0.5	0.25 0.10	2.2 1.8	1.35 1.15	1.3	1.15	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT343R						97-05-21

## Silicon MMIC amplifier

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**DEFINITIONS**

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

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**Australia:** 3 Figtree Drive, HOMEBUSH, NSW 2140,  
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**Austria:** Computerstr. 6, A-1101 WIEN, P.O. Box 213,  
Tel. +43 1 60 101 1248, Fax. +43 1 60 101 1210

**Belarus:** Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,  
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Tel. +852 2319 7888, Fax. +852 2319 7700

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**Denmark:** Sydhavnsgade 23, 1780 COPENHAGEN V,  
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**Finland:** Sinikalliontie 3, FIN-02630 ESPOO,  
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Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

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Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510,  
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**Israel:** RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,  
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

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**Japan:** Philips Bldg 13-37, Kohnan 2-chome, Minato-ku,  
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Tel. +60 3 750 5214, Fax. +60 3 757 4880

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**South America:** Al. Vicente Pinzon, 173, 6th floor,  
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**Spain:** Balmes 22, 08007 BARCELONA,  
Tel. +34 93 301 6312, Fax. +34 93 301 4107

**Sweden:** Kottbygatan 7, Akalla, S-16485 STOCKHOLM,  
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**Turkey:** Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye,  
ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813

**Ukraine:** PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,  
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

**United Kingdom:** Philips Semiconductors Ltd., 276 Bath Road, Hayes,  
MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421

**United States:** 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,  
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